

KIT-CRD-3DD12P Buck Boost Evaluation Kit

Wolfspeed Power Marketing



Overview of KIT-CRD-3DD12P Evaluation Board

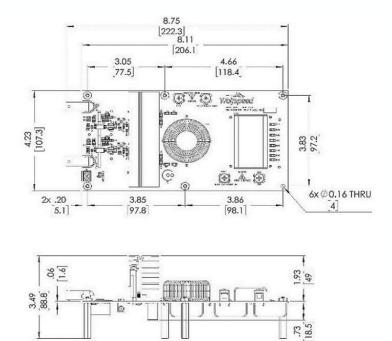
- Evaluate and optimize steady state and high speed switching performance of Wolfspeed C3MTM SiC MOSFETs and Schottky diodes
- Analyze the evaluation board in versatile power conversion topologies, such as Synchronous / Asynchronous
 Buck or Boost converter, Half Bridge and Full Bridge (Please note: Full Bridge require 2 Evaluation Kits)
- Board features footprints for both 3 and 4 lead TO-247 packages of C3M[™] SiC MOSFETs
- Compatible with both TO-247 and TO-220 packages of SiC Schottky diodes
- Does not require an additional capacitor to run the evaluation board in the buck or boost converter topologies
- Two (2) dedicated gate drivers available on the board for each C3M™ SiC MOSFET
- Includes (2) 1200 V, 75mΩ (C3MTM) SiC MOSFETs in a TO-247-4 Package with the testing hardware



(KIT-CRD-3DD12P Evaluation Board)

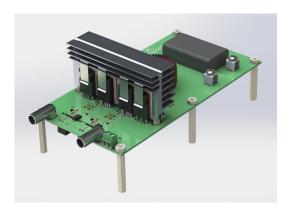
Physical layout of KIT-CRD-3DD12P Evaluation Board

• Physical dimensions of a fully assembled KIT-CRD-3DD12P evaluation board are 222 mm X 97 mm X 49 mm



(Physical layout of the evaluation board)

Electrical Specifications of KIT-CRD-3DD12P

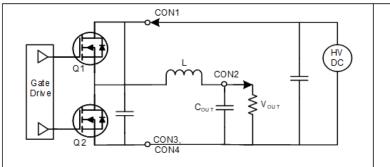


Max Input Voltage	800V		
Max Output Voltage	800V		
Max Output Power	2.5kW**		
V _{CC} (Logic Power)	ver) 15VDC		
Frequency	100khz**		

(** Power and frequency limits are based on the inductor. Different output power and switching frequency can be achieved with a different inductor.)

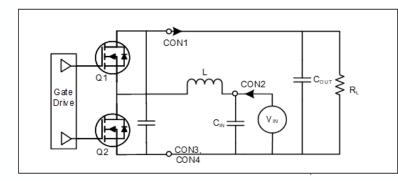
Example Topologies

• KIT-CRD-3DD12P evaluation board as a synchronous buck converter:



- Step down voltage
- MOSFET body diode is used instead of flyback diode
- CON1 is input
- · CON2 is output
- CON3, CON4 is ground

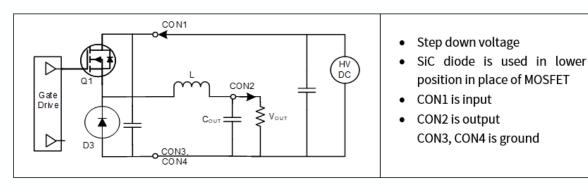
KIT-CRD-3DD12P evaluation board as a synchronous boost converter:



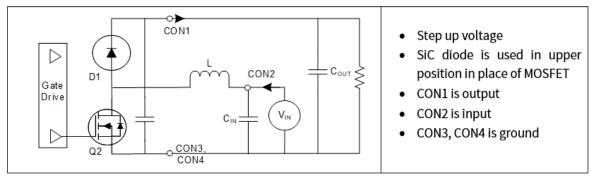
- · Step up voltage
- MOSFET body diode is used instead of flyback diode
- CON1 is output
- CON2 is input
- CON3, CON4 is ground

Example Topologies (Continued)

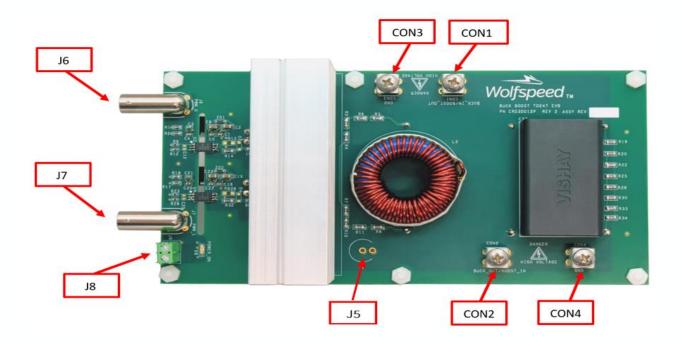
KIT-CRD-3DD12P evaluation board as a asynchronous buck converter:



KIT-CRD-3DD12P evaluation board as a asynchronous boost converter:

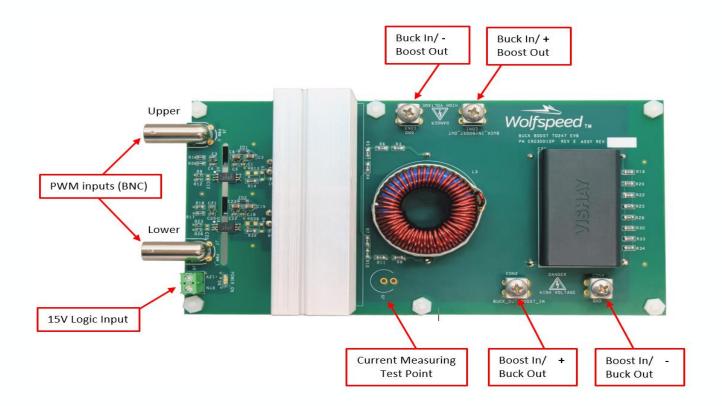


Physical Location of Terminals and connectors



(Top side view of the evaluation board with the physical location of terminals and connectors)

Description of Terminals and connectors



(Top side view of the evaluation board with the description of terminals and connectors)

Test Point Locations (For TO-247-4L MOSFETs)

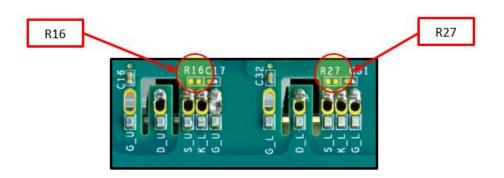
- · Cree's KIT-CRD-3DD12P evaluation board comes in a TO-247-4L configuration by default
- An SMA connector also included in the evaluation kit for capturing clean switching waveforms



(Bottom side view of the evaluation board with the identification of Test Point Locations)

Configuring Evaluation Board for TO-247-3L MOSFETs

• To convert either the upper or the lower MOSFET position into a TO-247-3L configuration, a 0Ω 0603 type resistor must be populated in each resistor position (R16, R27) located on the bottom side of the PCB



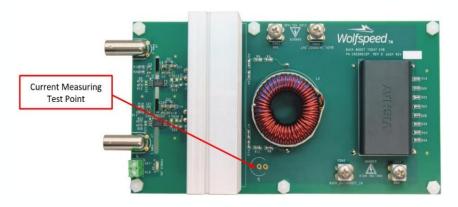
Device	Resistor	
Upper MOSFET (Q1)	R16	
Lower MOSFET (Q2)	R27	

(Location of resistors (R16 & R27) on the bottom side of the evaluation board)

(Description of resistors (R16 & R27)

Current Sensing

- Cree's KIT-CRD-3DD12P, Buck-Boost Evaluation Kit comes with a placeholder (J5) (Current Measuring Test Point)
- Users can sense current waveforms by placing a current viewing device at J5





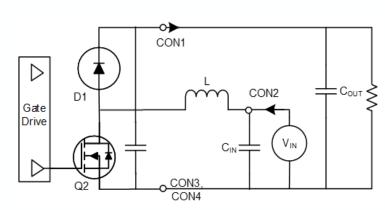
(Top View of the evaluation board with current measuring test point)

(View of current sensing device installed on the evaluation board)

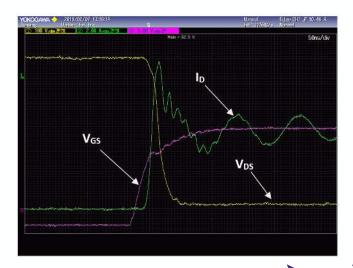
(Please note that Cree's KIT-CRD-3DD12P, Buck-Boost Evaluation Kit will not work without a current sensing device or without populating a jumper at J5)

Example Application 1 (Boost Converter)

- Cree's KIT-CRD-3DD12P, Buck-Boost Evaluation Kit can been analyzed as a Asynchronous Boost Converter
- In this case, a SiC diode is placed at the upper position while a SiC MOSFET is placed at the lower position
- By placing oscilloscope probes at the appropriate test point locations, clean switching waveforms of V_{GS} , V_{DS} (Drain to Source Voltage) and I_D (Drain Current) can be viewed on oscilloscope



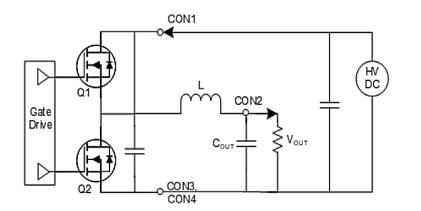
(Asynchronous Boost Converter)

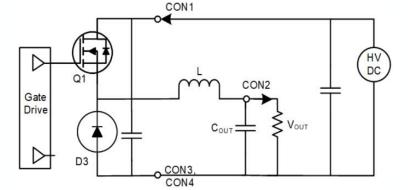


(Switching Waveforms)

Example Application 2 (Buck Converter)

- Cree's KIT-CRD-3DD12P, Buck-Boost Evaluation Kit can been analyzed as a Synchronous and Asynchronous Buck
 Converter as well
- In the case of Synchronous Buck Converter, a SiC MOSFET is placed both at the upper and the lower positions
- While in Asynchronous Buck Converter, a SiC MOSFET is placed at the upper position and a SiC diodes is placed at the lower position



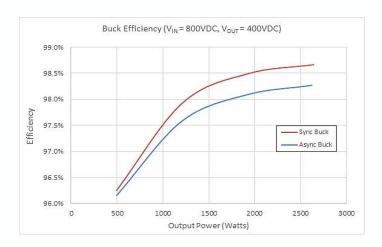


(Synchronous Buck Converter)

(Asynchronous Buck Converter)

Example Application 2 (Buck Converter) (Continued)

- By analyzing Cree's KIT-CRD-3DD12P evaluation board at full power (2.5 kW) in both Asynchronous and Synchronous Buck converter topologies, favorable efficiency results can be achieved
- In Synchronous Buck Converter arrangement, at full power (2.5 kW), Cree SiC MOSFETs and the inductor remains well within the thermal limits



(Synchronous / Asynchronous Buck Converter Efficiency Vs Output Power)



(Thermal Scan of MOSFETs)



(Thermal Scan of Inductor)

Summary

- Evaluate and optimize the steady state and dynamic switching performance of both SiC (C3MTM)
 MOSFETs (TO-247-3, TO-247-4) and SiC Schottky diodes (TO-247, TO-220)
- Analyze the evaluation board in versatile power conversion topologies i.e. Synchronous / Asynchronous Buck or Boost converter, Half Bridge and Full Bridge (Require 2 kits)
- No additional capacitor required to run the evaluation board in the boost or buck converter topologies
- By using Cree's KIT-CRD-3DD12P evaluation board, users can conveniently measure ringing free switching waveforms (V_{GS} , V_{DS} etc..) and the system level efficiency at full power (2.5 kW) while maintaining the temperature of MOSFETs and the Inductor well within the limits

(If user require more information about the detailed operation of Cree's KIT-CRD-3DD12P evaluation board please review Cree's KIT-CRD-3DD12P evaluation board's Application Note)

(If user have questions about Cree's KIT-CRD-3DD12P evaluation board, please contact Cree at sic power@cree.com)

Appendix

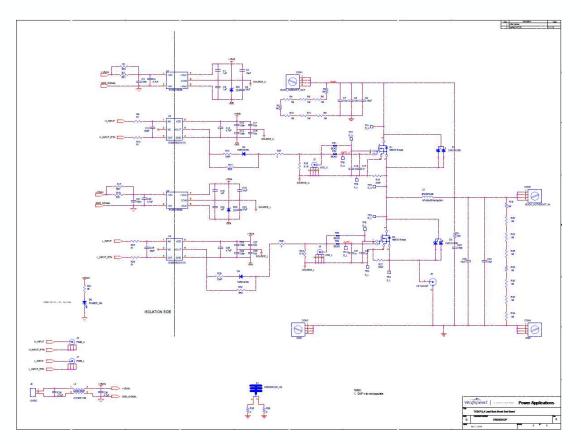


Package Contents of Cree's KIT-CRD-3DD12P Evaluation Board

(If user require more information about the detailed operation of Cree's KIT-CRD-3DD12P evaluation board please review Cree's KIT-CRD-3DD12P evaluation board's Application Note)

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Schematic of KIT-CRD-3DD12P Evaluation Board



Note: a larger copy of the schematic may be obtained upon request by contacting Cree at **sic_power@cree.com**

Package contents of KIT-CRD-3DD12P Evaluation Board



222 mm X 97 mm X 49 mm

ITEM NO.	QTY.	DESCRIPTION	Mfg.	P/N
1	1	CRD-3DD12P rev22 Buck Boost Eval Board Assy.	Make	CRD-3DD12P
2	4	High force clip	Aavid Thermalloy	MAX03-HNG
3	1	Heat sink extrusion, custom length 4 in.	Aavid Thermalloy	780603U04000G
4	2	MOSFET, 1200V, 75 mohm	Cree	C3M0075120K
5	4	Kapton Thermal Interface (Cut to 22mm x 29mm rectangle)	Fischer Elektronik	KAP 1 P
6	1	Foam insert top	Make	See drawing
7	1	Conductive foam strip	Make	See drawing
8	1	S/N Label	Make	n/a
9	1	Cover graphic Label	Make	n/a
10	1	Foam insert	Make	See drawing
11	6	Male-Female Threaded Hex Standoff Nylon 6/6, 1/4" Hex Size, 1-1/2" Long, 6-32 to 6-32	McMaster-Carr	92745A348
12	2	Spacer, 1/4" OD, 5/32" Length, un-threaded Al, #6 screw	McMaster-Carr	92510A031
13	6	Nylon Hex Nut, 6-32 Thread Size	McMaster-Carr	94812A300
14	2	Phillips Round Head Screw, M3 x 0.5 mm Thread, 10 mm Long	McMaster-Carr	92005A120
15	2	Steel Split Lock Washer for M3 Screw Size, 3.4 mm ID, 6.2 mm OD	McMaster-Carr	91202A222
16	1	Package Box	Uline	S-16677
17	3	2"x3" 4mil re-closeable poly bag	Uline	S-12269
18	1	ESD Label on box	Uline	S-2245
19	2	CONN ADAPT SMA PLUG TO BNC JACK	Amphenol	242102

